Refine Search

Search Results -

Term	Documents
SEMICONDUCTOR	525409
SEMICONDUCTORS	65073
DEVICE	2387636
DEVICES	1762776
PIXELS	145606
PIXEL	161222
DATA	1484499
DATUM	22302
LINE	2481255
LINES	1513345
DRIVE	1143702
((SEMICONDUCTOR ADJ DEVICE AND PIXELS AND DATA ADJ LINE ADJ DRIVE ADJ CIRCUIT\$1 AND MEMNORY AND MEMORY ADJ CONTROL ADJ CIRCUIT AND FIRTS ADJ SUBSTRATE AND SECOND ADJ SUBSTATE).CLM.).PGPB,USPT.	0

There are more results than shown above. Click here to view the entire set.

Database:	US Pre-Grant Publication Full-Tex US Patents Full-Text Database US OCR Full-Text Database EPO Abstracts Database JPO Abstracts Database Derwent World Patents Index IBM Technical Disclosure Bulletin		
Search:	L14	<u>_</u>	Refine Search
	Recall Text 🗢	Clear	Interrupt
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Search History

DATE: Monday, March 13, 2006 Printable Copy Create Case

Inventor Search

Set

Interference Search

<u>Set</u>

Name side by side	Query	<u>Hit</u> Count	Name result set
DB=	PGPB,USPT; PLUR=YES; OP=ADJ		
<u>L14</u>	(semiconductor adj device and pixels and data adj line adj drive adj circuit\$1 and memnory and memory adj control adj circuit and firts adj substrate and second adj substate).CLM.	0	<u>L14</u>
<u>L13</u>	(semiconductor adj device and pixels and data adj line adj drive adj circuit\$1 and memnory and memory adj control adj circuit and firts adj substrate and second adj substate).CLM.	0	<u>L13</u>
<u>L12</u>	koyama-jun	723	<u>L12</u>
DB=	PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=ADJ		
<u>L11</u>	L10 and data adj line adj dirver\$1	0	<u>L11</u>
<u>L10</u>	L9 and memory adj control adj circuit	8	<u>L10</u>
<u>L9</u>	(memory or storage) same second adj substrate	1417	<u>L9</u>
<u>L8</u>	memory adj control adj circuit\$1 same second adj substrate	2	<u>L8</u>
<u>L7</u>	L6 and memory adj control adj circuit and second adj substrate	2	<u>L7</u>
<u>L6</u>	L3 and second adj substrate	1848	<u>L6</u>
<u>L5</u>	L3 and (memory or storage) same memory adj control adj circuit same second adj substrate	0	<u>L5</u>
<u>L4</u>	L3 and second substrate same data adj line adj driver adj circuit\$1	0	<u>L4</u>
<u>L3</u>	L2 and @py<=2000	1848	<u>L3</u>
<u>L2</u>	display\$1 same first adj substrate same second substrate	8432	<u>L2</u>
<u>L1</u>	display\$1	2063057	<u>L1</u>

END OF SEARCH HISTORY

Freeform Search

	US Pre-Grant Publication Full-Text Database		
	US Patents Full-Text Database		
	US OCR Full-Text Database		
Database:	EPO Abstracts Database		
	JPO Abstracts Database		
	Derwent World Patents Index		
	IBM Technical Disclosure Bulletins		
	L10 and data adj line adj dirver\$1		
Term:	210 and data day 11ne day d21ve1v1		
101111			
Display:	Documents in Display Format: TI Starting with Number 1		
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Generate:	C Hit List @ Hit Count C Side by Side C Image		

	Search Clear Interrupt		
		······	
Search History			

DATE: Monday, March 13, 2006 Printable Copy Create Case

<u>Set</u> <u>Name</u> side by side	Query	<u>Hit</u> Count	<u>Set</u> <u>Name</u> result set
DB=P	GPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=ADJ		
<u>L11</u>	L10 and data adj line adj dirver\$1	0	<u>L11</u>
<u>L10</u>	L9 and memory adj control adj circuit	8	<u>L10</u>
<u>L9</u>	(memory or storage) same second adj substrate	1417	<u>L9</u>
<u>L8</u>	memory adj control adj circuit\$1 same second adj substrate	2	<u>L8</u>
<u>L7</u>	L6 and memory adj control adj circuit and second adj substrate	2	<u>L7</u>
<u>L6</u>	L3 and second adj substrate	1848	<u>L6</u>
<u>L5</u>	L3 and (memory or storage) same memory adj control adj circuit same second adj substrate	0	<u>L5</u>
<u>L4</u>	L3 and second substrate same data adj line adj driver adj circuit\$1	0	<u>L4</u>
<u>L3</u>	L2 and @py<=2000	1848	<u>L3</u>
<u>L2</u>	display\$1 same first adj substrate same second substrate	8432	<u>L2</u>
<u>L1</u>	display\$1	2063057	<u>L1</u>

END OF SEARCH HISTORY